# imall

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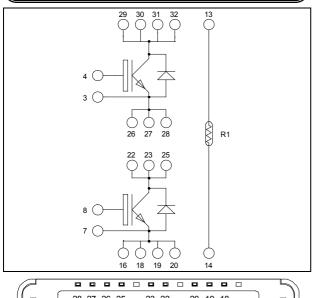
# Contact us

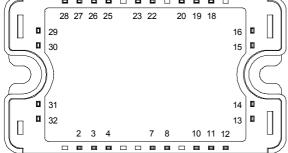
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Phase leg Trench + Field Stop IGBT3 Power Module





Pins 29/30/31/32 must be shorted together Pins 26/27/28/22/23/25 must be shorted together to achieve a phase leg Pins 16/18/19/20 must be shorted together

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		600	V
I <sub>C</sub>	Continuous Collector Current	$T_C = 25^{\circ}C$	290	
1 <sub>C</sub>	Continuous Conector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	200	А
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	400	
V <sub>GE</sub>	Gate – Emitter Voltage		±20	V
PD	Maximum Power Dissipation	$T_C = 25^{\circ}C$	750	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	400A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

# APTGT200A60T3AG

### $V_{CES} = 600V$ $I_{C} = 200A$ @ Tc = 100°C

### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

### Features

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Very low stray inductance
- Kelvin emitter for easy drive
- Internal thermistor for temperature monitoring
- High level of integration
- AlN substrate for improved thermal performance

### Benefits

- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

1 - 6



### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified • ...

Electrical Characteristics								
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} =$	= 600V			250	μA	
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.5	1.9	V	
V <sub>CE(sat)</sub>	Conector Ennitier Saturation Voltage	$I_{\rm C} = 200 {\rm A}$	$T_{j} = 150^{\circ}C$		1.7		v	
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 2 \text{ mA}$		5.0	5.8	6.5	V	
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE}$	=0V			400	nA	

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			12.3		
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 25V$			0.8		nF
Cres	Reverse Transfer Capacitance	f = 1 MHz			0.4		
Q <sub>G</sub>	Gate charge	$V_{GE} = \pm 15V$ ; $V_{C}$ $I_{C} = 200A$	<sub>CE</sub> =300V		2.2		μC
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switch	hing (25°C)		115		
Tr	Rise Time	$V_{GE} = \pm 15V$			45		ns
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 200A$			225		
$T_{\rm f}$	Fall Time	$R_G = 2\Omega$			55		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (150°C)			130		
T <sub>r</sub>	Rise Time	$V_{GE} = \pm 15V$			50		ns
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 300V$ $I_C = 200A$			300		
T <sub>f</sub>	Fall Time	$R_G = 2\Omega$	-		70		
Eon	Turn on Energy	• GE =1.5 •	$T_j = 25^{\circ}C$		1		mJ
Lon	Turn on Energy			$T_{j} = 150^{\circ}C$		1.8	
Б	Turn off Enorgy	D 20	$T_j = 25^{\circ}C$		5.7		mI
E <sub>off</sub>	Turn off Energy		$T_{j} = 150^{\circ}C$		7		mJ
I <sub>sc</sub>	Short Circuit data	$V_{GE} \leq 15V ; V_{Bus}$ $t_p \leq 6\mu s ; T_j = 15$			1000		А

### **Reverse diode ratings and characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			600			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =600V	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$			250 500	μΑ
I <sub>F</sub>	DC Forward Current		$T_c = 80^{\circ}C$		200	200	А
V	Diode Forward Voltage	$I_{\rm F} = 200 {\rm A}$	$T_i = 25^{\circ}C$		1.6	2	V
$V_{\rm F}$	Diode Forward Voltage	$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		v
t	Reverse Recovery Time		$T_j = 25^{\circ}C$		125		ns
t <sub>rr</sub>	Reverse Recovery Time		$T_{j} = 150^{\circ}C$		220		115
0	Reverse Recovery Charge $V_R = 300V$		$T_j = 25^{\circ}C$		9		чС
Q <sub>rr</sub>				$T_{i} = 150^{\circ}C$	20		μC
Er	Reverse Recovery Energy		$T_j = 25^{\circ}C$		2.2		mI
			$T_{j} = 150^{\circ}C$		4.8		mJ

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# APTGT200A60T3AG

### Thermal and package characteristics

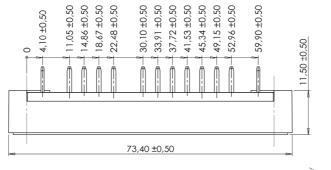
Symbol	Characteristic		Min	Тур	Max	Unit	
R <sub>thJC</sub>	Junction to Case Thermal Resistance		IGBT			0.20	°C/W
<b>R</b> <sub>th</sub> JC			Diode			0.31	
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range		-40		175		
T <sub>STG</sub>	Storage Temperature Range		-40		125	°C	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight				110	g	

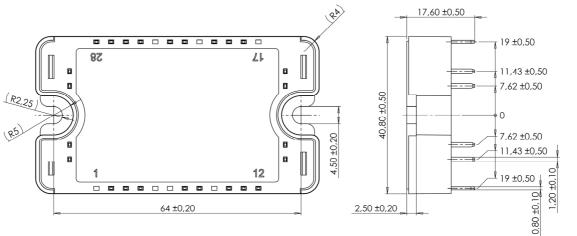
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic			Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		$T_C = 100^{\circ}C$		4		%

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

### SP3 Package outline (dimensions in mm)



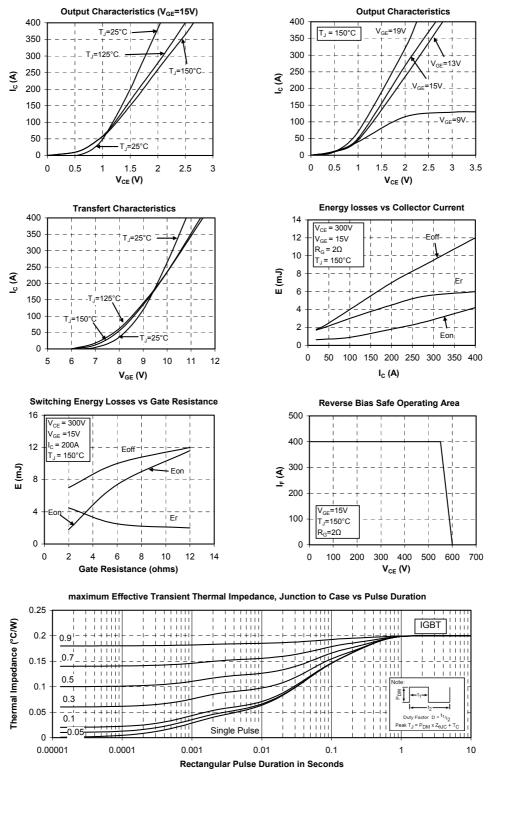


See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

APTGT200A60T3AG-Rev 2 October, 2012



### **Typical Performance Curve**



# APTGT200A60T3AG-Rev 2 October, 2012

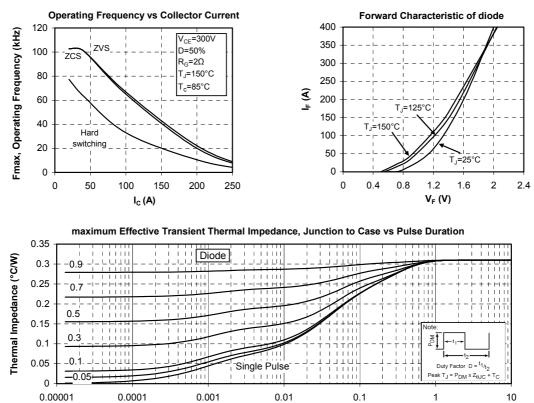
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## APTGT200A60T3AG



# **APTGT200A60T3AG**

1



0.01 **Rectangular Pulse Duration in Seconds** 

0.001



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